Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:	
Glass	
Overall Length:	
Between 0.195 inches	and 0.350 inches
Terminal Length:	
1.000 inches	
Overall Diameter:	
Between 0.215 inches	and 0.265 inches
	lectrically Connected To Case:
Cathode	
Mounting Method:	
Terminal	
Features Provided:	
Hermetically sealed ca	se
Semiconductor Mater	ial:
Silicon	
Voltage Rating In Vol	ts Per Characteristic:
4.3 regulator voltage	
Current Rating Per Cl	naracteristic:
213.00 milliamperes so	purce cutoff current horsepower metric
Power Rating Per Cha	aracteristic:
1.0 watts small-signal i	nput power, common-collector preset
Maximum Operating	Tempurature Per Measurement Point:
175.0 degrees celsius	ambient air
Test Data Document:	
81349-mil-s-19500 spe	cification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; excludes comr	nercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and perf	formance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Q	uantity:
2 uninsulated wire lead	
Specification Data:	
81349-mil-s-19500/115	government specification
Shelf Life:	
N/a	
Unit Of Measure:	
 Demilitarization:	
Yes - demil/mli	
Fiig:	
A110a0	